New Jersey Semi-Conductor Products, Inc.

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1N56 GOLD BONDED GERMANIUM DIODE

FEATURES

Low forward voltage drop—low power consumption Thirty years of proven reliability—one million hours mean time between failures (MTBF) Very low noise level Metallurgically bonded

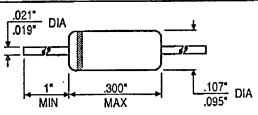
ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage Peak Forward Current Operating Temperature Range Average Power Dissipation ⁻30 Volts 500 mA - 65 °C to 85 °C 80 mW

ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min	Max	Unit	T℃	
Peak Inverse Voltage Reverse Current	PIV Ir	1 mA 30 V	30	300	V μA	25 °C 25 °C	
Forward Voltage	Vf	15 mA		1	v	25 °C	

MECHANICAL





NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors